



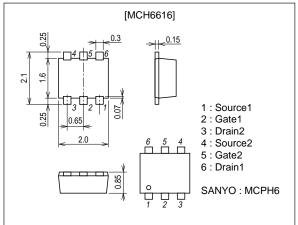
Ultrahigh-Speed Switching Applications

Features

- · Low ON-resistance.
- · Ultrahigh-speed switching.
- · 2.5V drive.
- Composite type with 2 MOSFETs contained in a single package, facilitating high-density mounting.

Package Dimensions

unit : mm 2173A



Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	VDSS		20	V
Gate-to-Source Voltage	VGSS		±10	V
Drain Current (DC)	ID		1.6	А
Drain Current (Pulse)	IDP	PW≤10μs, duty cycle≤1%	6.4	Α
Allowable Power Dissipation	PD	Mounted on a ceramic board (900mm ² X0.8mm)1unit	0.8	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			l lm:s
			min	typ	max	Unit
Drain-to-Source Breakdown Voltage	V(BR)DSS	I _D =1mA, V _G S=0	20			V
Zero-Gate Voltage Drain Current	IDSS	V _{DS} =20V, V _{GS} =0			1	μΑ
Gate-to-Source Leakage Current	IGSS	V _{GS} =±8V, V _{DS} =0			±10	μΑ
Cutoff Voltage	VGS(off)	V _{DS} =10V, I _D =1mA	0.4		1.3	V
Forward Transfer Admittance	yfs	V _{DS} =10V, I _D =0.8A	1.6	2.4		S
Static Drain-to-Source On-State Resistance	R _{DS} (on)1	I _D =0.8A, V _{GS} =4V		180	230	mΩ
	RDS(on)2	ID=0.4A, VGS=2.5V		220	310	mΩ
	Rps(on)3	ID=0.1A, VGS=1.8V		300	450	mΩ

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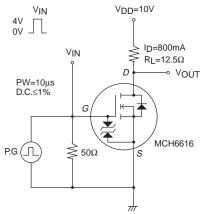
SANYO Electric Co.,Ltd. Semiconductor Company
TOKYO OFFICE Tokyo Bldg., 1-10, 1 Chome, Ueno, Taito-ku, TOKYO, 110-8534 JAPAN

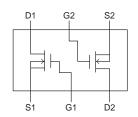
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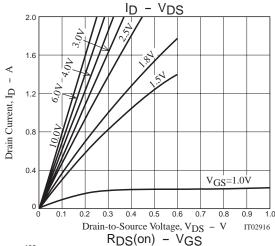
Parameter	Symbol	Conditions		Ratings		
	Symbol		min	typ	max	Unit
Input Capacitance	Ciss	V _{DS} =10V, f=1MHz		105		pF
Output Capacitance	Coss	V _{DS} =10V, f=1MHz		23		pF
Reverse Transfer Capacitance	Crss	V _{DS} =10V, f=1MHz		15		pF
Turn-ON Delay Time	t _d (on)	See specified Test Circuit		6		ns
Rise Time	tr	See specified Test Circuit		16		ns
Turn-OFF Delay Time	t _d (off)	See specified Test Circuit		19		ns
Fall Time	tf	See specified Test Circuit		8		ns
Total Gate Charge	Qg	V _{DS} =10V, V _{GS} =4V, I _D =1.6A		1.4		nC
Gate-to-Source Charge	Qgs	V _{DS} =10V, V _{GS} =4V, I _D =1.6A		0.3		nC
Gate-to-Drain "Miller" Charge	Qgd	V _{DS} =10V, V _{GS} =4V, I _D =1.6A		0.3		nC
Diode Forward Voltage	V _{SD}	I _S =1.6A, V _G S=0		0.92	1.2	V

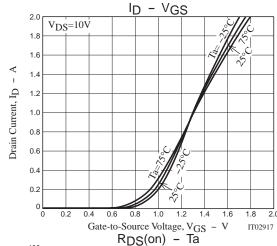
Switching Time Test Circuit

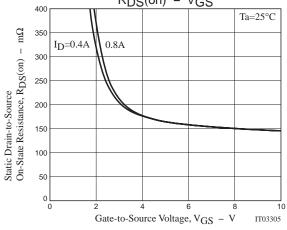
Electrical Connection

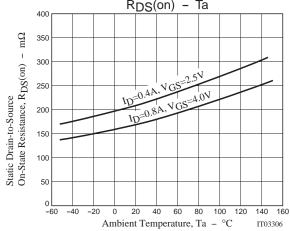


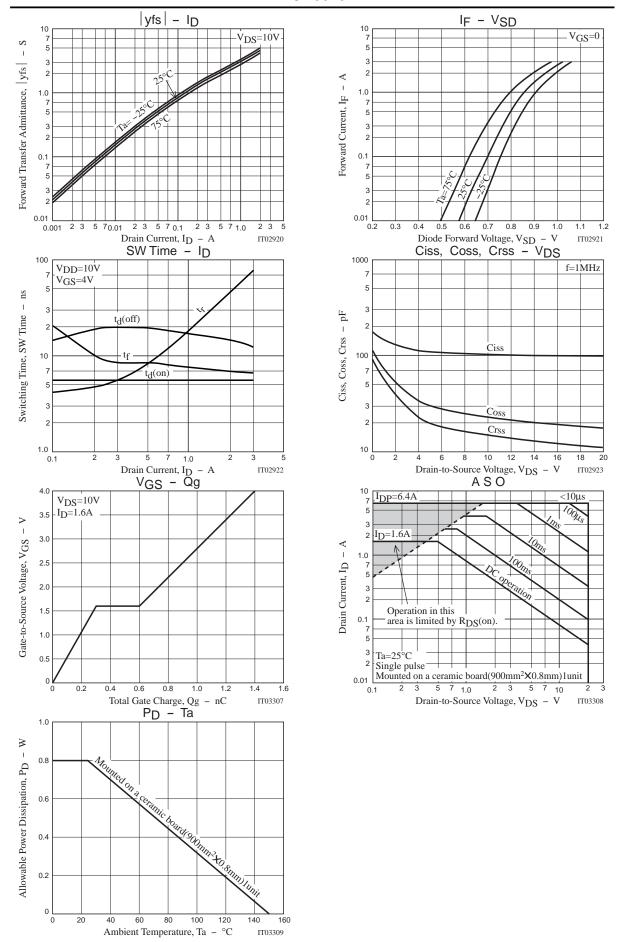












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